

General Purpose Schottky Barrier Diode

General Description

These Schottky barrier diodes are designed for high-speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conductions. Miniature surface mount package is excellent for hand-held and portable applications where space is limited.

Features and Benefits

- · Low forward drop voltage and low leakage current
- Very low switching time
- Full lead (Pb)-free device and RoHS compliant device
- Available in "Green" device

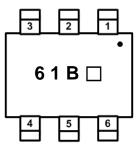
Applications

- · General purpose and high speed switching
- Protection circuit and voltage clamping

Ordering Information

Part Number	ber Marking Code Package		Packaging		
SUB610	61B 🗆	SOT-23F	Tape & Reel		

Marking Information



61B = Specific Device Code

□ = Year & Week Code Marking

Pinning Information

Pin	Description	Simplified Outline	Graphic Symbol
1	Cathode (Diode 1)		
2	Cathode (Diode 2)	3 2 1	
3	Cathode (Diode 3)	•	
4	Anode (Diode 3)		
5	Anode (Diode 2)	4 5 6	
6	Anode (Diode 1)		



SOT-363



Absolute Maximum Ratings (Tamb=25°C, Unless otherwise specified)

Characteristic	Symbol	Ratings	Unit	
Peak reverse voltage	V _{RM}	40	V	
DC reverse voltage	V _R	30	V	
Repetitive peak forward current	I _{FRM}	0.5	А	
Forward current	I _F	0.2	A	
Non-repetitive peak forward surge current(t=10ms)	I _{FSM}	2	А	
Power dissipation ¹⁾	P _D	150	mW	

¹⁾ Device mounted on FR-4 board with recommended pad layout.

Thermal Characteristics (T_{amb}=25°C, Unless otherwise specified)

Characteristic	Symbol	Ratings	Unit	
Thermal resistance, junction to ambient 1)	R _{th(j-a)}	833	°C/W	
Operating junction temperature	Tj	150	°C	
Storage temperature range	T _{stg}	-55 ~ 150	°C	

¹⁾ Device mounted on FR-4 board with recommended pad layout.

Electrical Characteristics (T_{amb}=25°C, Unless otherwise specified)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Forward voltage ²⁾	V _{F(1)}	I _F =10mA	-	-	0.4	V
	V _{F(2)}	I _F =30mA	-	-	0.5	V
Reverse leakage current 3)	I _R	V _R =30V	-	-	1	μA
Total capacitance	C _T	V _R =1V, f=1MHz	-	-	10	pF
Reverse recovery time	t _{rr}	$I_F = I_R = 10 \text{mA}, I_{R(REC)} = 1 \text{mA}$	-	-	5	ns

²⁾ Pulse test: $t_P \leq 380 \mu$ s, Duty cycle $\leq 2\%$

³⁾ Pulse test: $t_P \le 5ms$, Duty cycle $\le 2\%$

Rating and Characteristic Curves

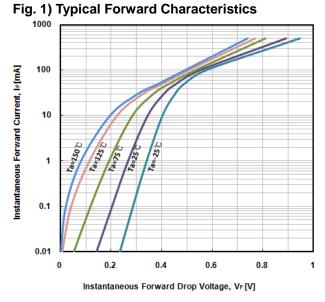
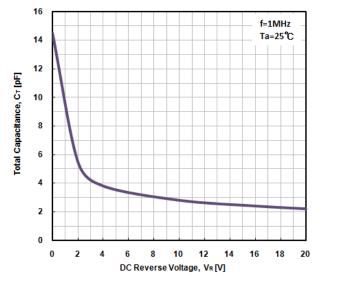
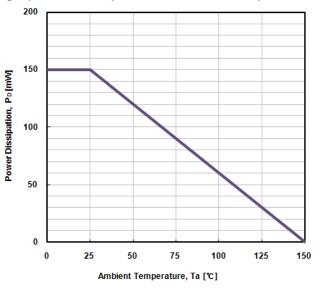


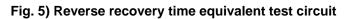
Fig. 3) Typical Total Capacitance Characteristics

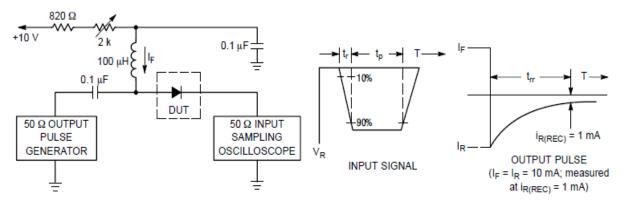


1000 Ta=150°C Instantaneous Reverse Leakage Current, I_R [uA] Ta=125°C 100 Ta=75℃ 10 1 Ta=25℃ 0.1 0.01 Ta=-25°C 0.001 0.0001 0 10 20 40 50 30 Instantaneous Reverse Voltage, V_R [V]

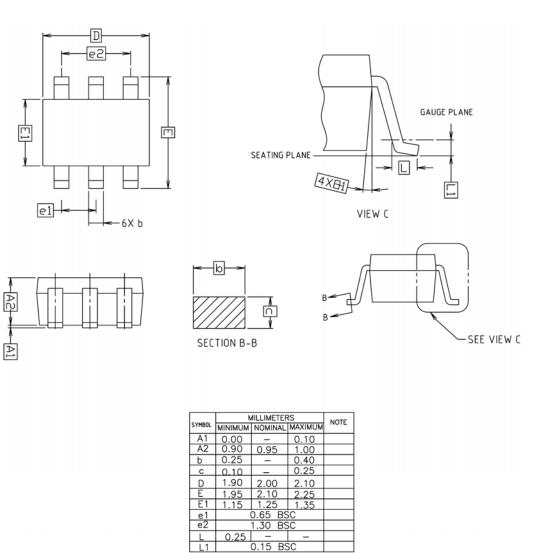
Fig. 4) Power dissipation vs. Ambient temperature



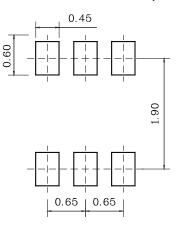




Package Outline Dimensions



※ Recommend PCB solder land (Unit : mm)



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